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High Performance Megabit SRAM

256Kx4 Monolithic CMOS Static RAM Commercial and Military

ADVANCE INFORMATION

The EDI84258CS/LPS/PS is a high speed, high performance, megabit density monolithic Static RAM with for both commercial and military applications. The device features separate input and output lines which provide fast read and write access to all memory loca-

It is intended for use in any application where large quantities of memory are required and /or board space is of prime concern.

Fully asynchronous, the EDI84258CS/LPS/PS requires no clocks or refreshing for operation. Inputs and outputs are TTL compatible and allow for direct interfacing with common system bus architecture.

Two low power versions are available, PS and LPS, for military products. The LPS version includes a 2V Data Retention Function for battery back-up operation.

Military product compliant to MIL-STD-883, Paragraph 1.2.1 is available.

Features

256Kx4 bit CMOS Static Random Access Memory

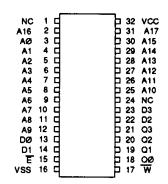
- Fast Access Times
 Commercial: 20, 25, and 35ns
 Military: 25, 35, 45, and 55ns
- E and G Functions for Bus Control
- TTL Compatible I/O
- Separate Data Inputs and Outputs
- Fully Static, No Clocks

Thru-hole and Surface Mount Package Options

- 32 Pin Dual-in-line Packages
 Ceramic DIP, 400 mils Wide, No. 102
 Plastic DIP, 400 mils Wide, No. 5
- 32 Lead Ceramic SOJ, No. 140
- 32 Lead Plastic SOJ, No. 7

Single +5V (±10%) Supply Operation

Pin Configuration and Block Diagram

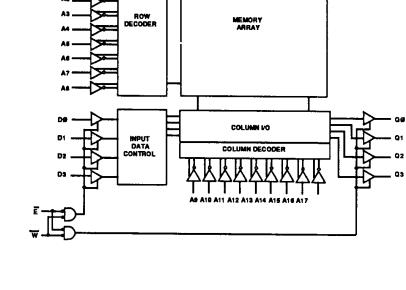




NC

<u>A</u> Ø-A17		Address Inputs
E W G		Chip Enable
$\overline{\mathbf{w}}$		Write Enable
G		Output Enable
DQØ-DQ3	Sep.	Common Data Input/Output
VCC	, -	Power (+5V±10%)
VSS		Ground

No Connection



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